



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

2SC4853A — NPN Epitaxial Planar Silicon Transistor

Low-Voltage, Low-Current

High-Frequency Amplifier Applications

Features

- Low-voltage, low-current operation : $f_T=5\text{GHz}$ typ
($V_{CE}=1\text{V}$, $I_C=1\text{mA}$) : $|S_{21e}|^2=7\text{dB}$ typ ($f=1\text{GHz}$)
: $\text{NF}=2.6\text{dB}$ typ ($f=1\text{GHz}$)

Specifications

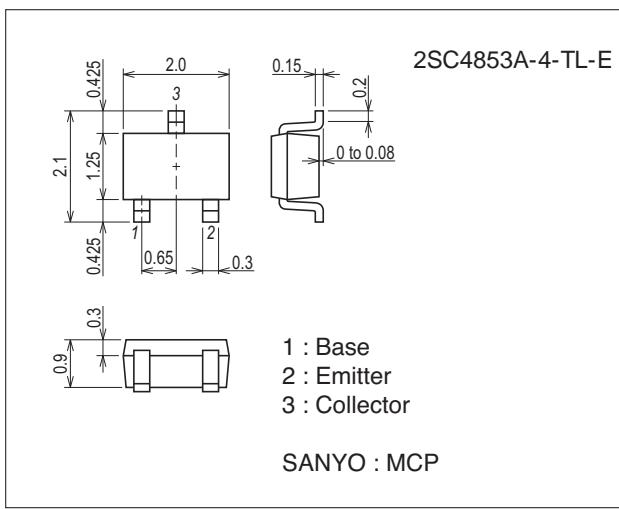
Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		12	V
Collector-to-Emitter Voltage	V_{CEO}		6	V
Emitter-to-Base Voltage	V_{EBO}		1.5	V
Collector Current	I_C		15	mA
Collector Dissipation	P_C		90	mW
Junction Temperature	T_J		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Package Dimensions

unit : mm (typ)

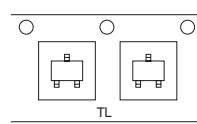
7023A-009



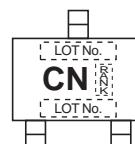
Product & Package Information

- Package : MCP
- JEITA, JEDEC : SC-70, SOT-323
- Minimum Packing Quantity : 3,000 pcs./reel

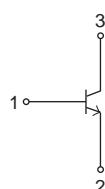
Packing Type: TL



Marking



Electrical Connection



Electrical Characteristics at $T_a=25^\circ C$

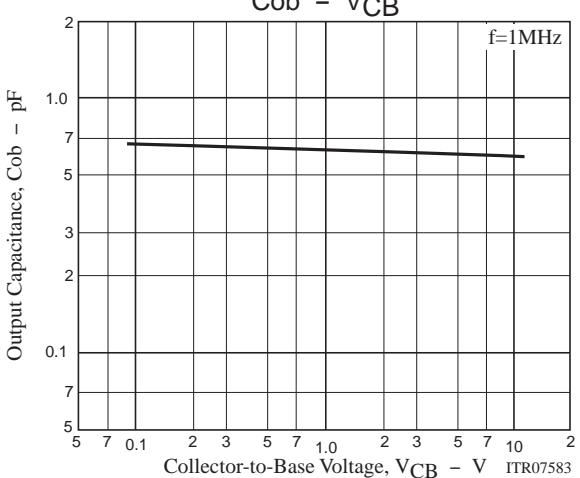
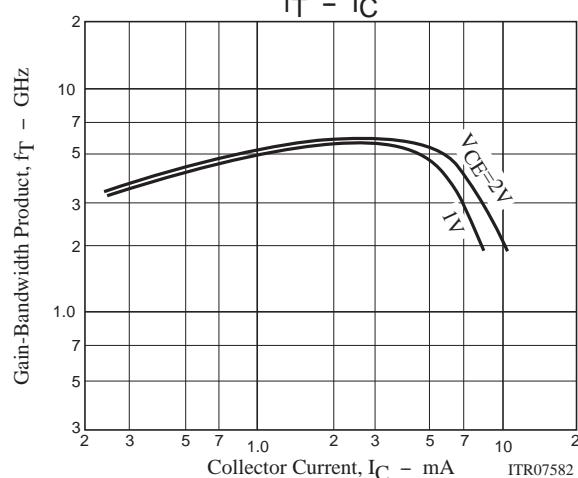
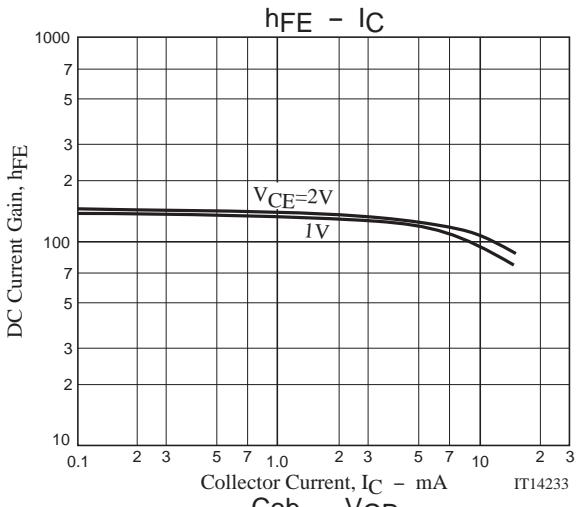
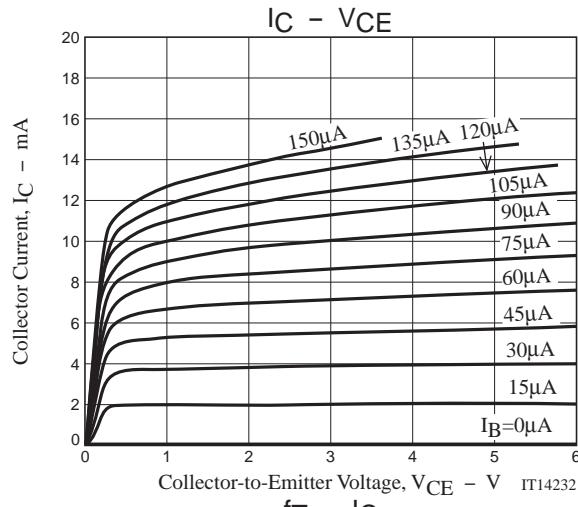
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=5V, I_E=0A$			1.0	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=1V, I_C=0A$			10	μA
DC Current Gain	h_{FE}	$V_{CE}=1V, I_C=1mA$	60*		270*	
Gain-Bandwidth Product	f_T	$V_{CE}=1V, I_C=1mA$		5		GHz
Output Capacitance	C_{ob}	$V_{CB}=1V, f=1MHz$		0.6	1.0	pF
Forward Transfer Gain	$ S_{21e} ^{21}$	$V_{CE}=1V, I_C=1mA, f=1GHz$	4.5	7		dB
	$ S_{21e} ^{22}$	$V_{CE}=2V, I_C=3mA, f=1GHz$		10.5		dB
Noise Figure	$NF1$	$V_{CE}=1V, I_C=1mA, f=1GHz$		2.6	4.5	dB
	$NF2$	$V_{CE}=2V, I_C=3mA, f=1GHz$		1.9		dB

* : The 2SC4853A is classified by 1mA h_{FE} as follows :

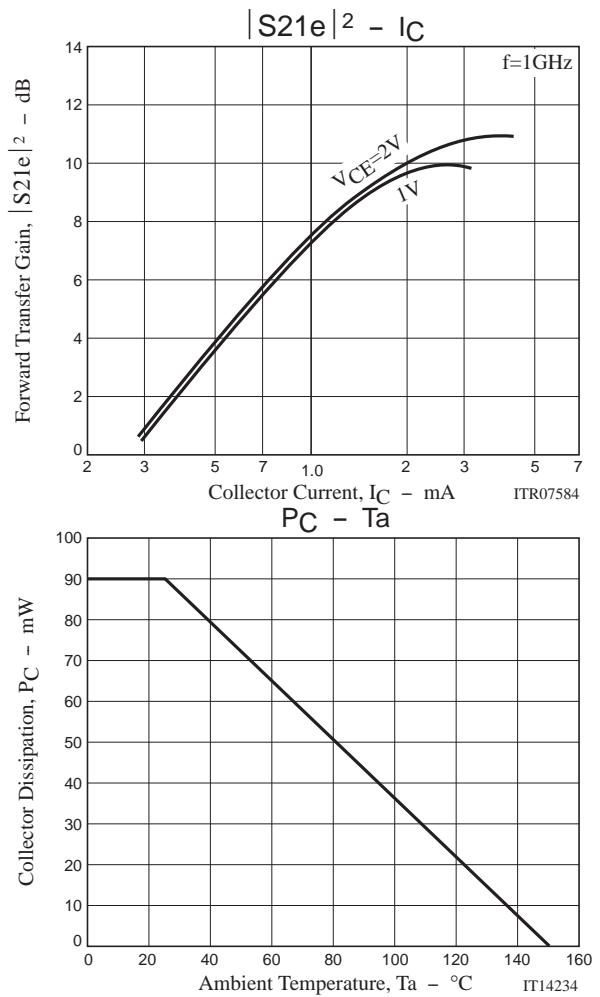
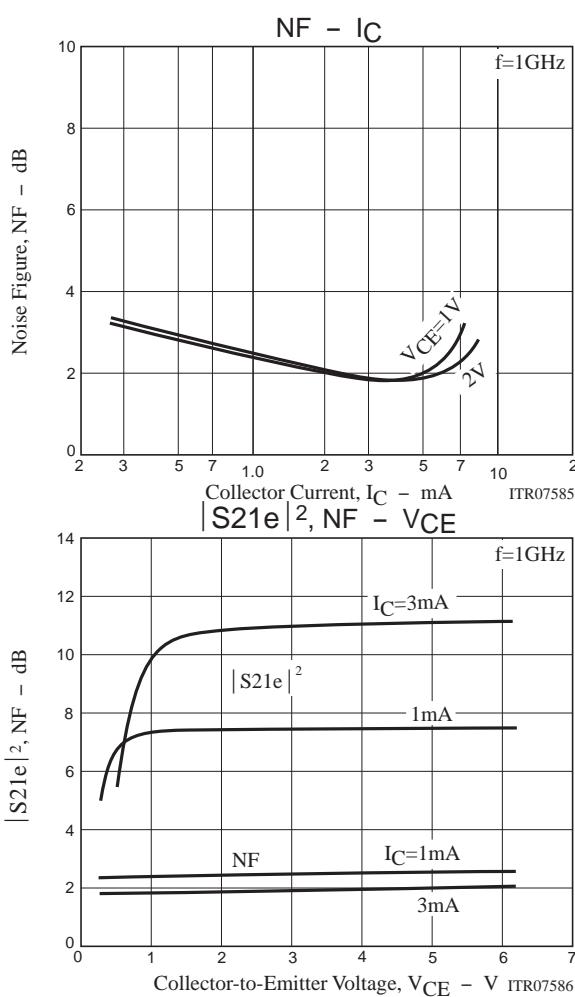
Rank	3	4	5
h_{FE}	60 to 120	90 to 180	135 to 270

Ordering Information

Device	Package	Shipping	memo
2SC4853A-4-TL-E	MCP	3,000pcs./reel	Pb Free



2SC4853A

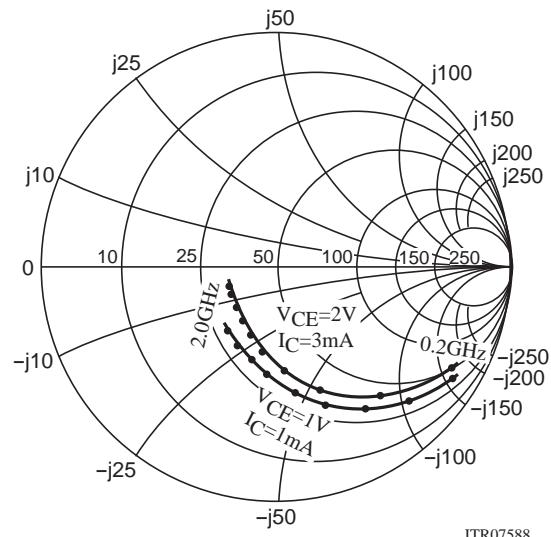


2SC4853A

S Parameters

S11e

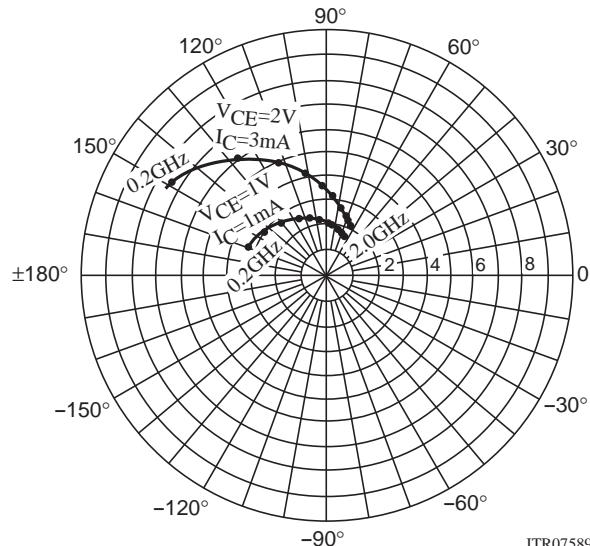
f=200MHz to 2000MHz(200MHz Step)



ITR07588

S21e

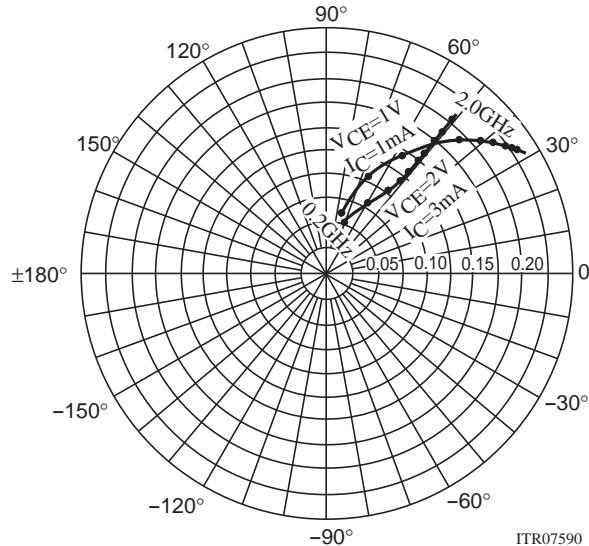
f=200MHz to 2000MHz(200MHz Step)



ITR07589

S12e

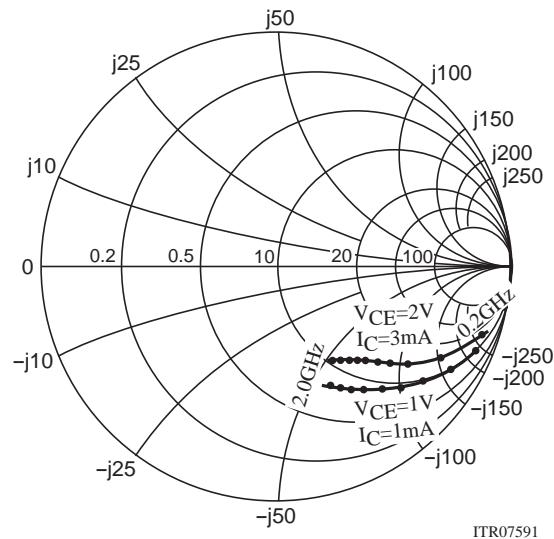
f=200MHz to 2000MHz(200MHz Step)



ITR07590

S22e

f=200MHz to 2000MHz(200MHz Step)



ITR07591

2SC4853A

S Parameters (Common emitter)

VCE=1V, IC=1mA, Z_O=50Ω

Freq(MHz)	S11	∠S11	S21	∠S21	S12	∠S12	S22	∠S22
200	0.940	-17.9	3.228	159.6	0.058	77.1	0.972	-12.2
400	0.863	-33.7	2.983	143.7	0.107	66.6	0.914	-22.7
600	0.778	-48.0	2.732	129.9	0.145	58.1	0.844	-31.7
800	0.698	-60.5	2.469	117.7	0.173	50.9	0.773	-39.6
1000	0.608	-73.5	2.320	106.2	0.195	45.4	0.717	-46.0
1200	0.546	-84.7	2.106	96.3	0.210	40.9	0.668	-51.7
1400	0.470	-96.2	1.977	87.1	0.129	37.6	0.624	-56.5
1600	0.418	-106.4	1.826	78.8	0.224	35.3	0.590	-60.6
1800	0.388	-117.3	1.700	72.2	0.230	33.8	0.562	-64.3
2000	0.354	-127.0	1.615	65.9	0.234	32.9	0.546	-67.5

VCE=2V, IC=3mA, Z_O=50Ω

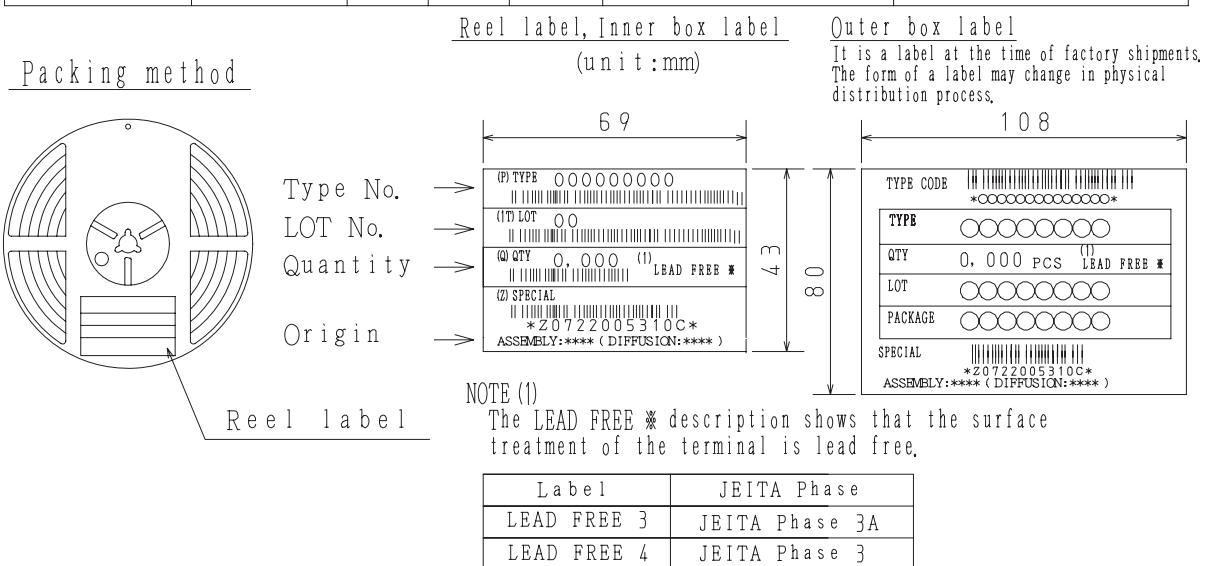
Freq(MHz)	S11	∠S11	S21	∠S21	S12	∠S12	S22	∠S22
200	0.839	-30.6	7.428	149.3	0.050	71.4	0.916	-18.3
400	0.672	-53.7	6.016	128.5	0.083	60.6	0.778	-30.2
600	0.536	-71.7	4.908	113.6	0.105	55.1	0.672	-37.1
800	0.431	-85.7	4.073	101.9	0.121	52.5	0.597	-41.9
1000	0.360	-99.0	3.494	92.7	0.135	51.4	0.548	-45.7
1200	0.310	-111.4	3.033	84.4	0.150	50.9	0.514	-49.2
1400	0.265	-122.6	2.694	77.4	0.162	50.9	0.492	-52.3
1600	0.242	-134.7	2.422	70.9	0.175	51.0	0.475	-55.6
1800	0.228	-148.0	2.205	65.9	0.189	51.1	0.461	-59.0
2000	0.217	-157.2	2.061	60.8	0.205	51.0	0.456	-61.8

Embossed Taping Specification

2SC4853A-4-TL-E

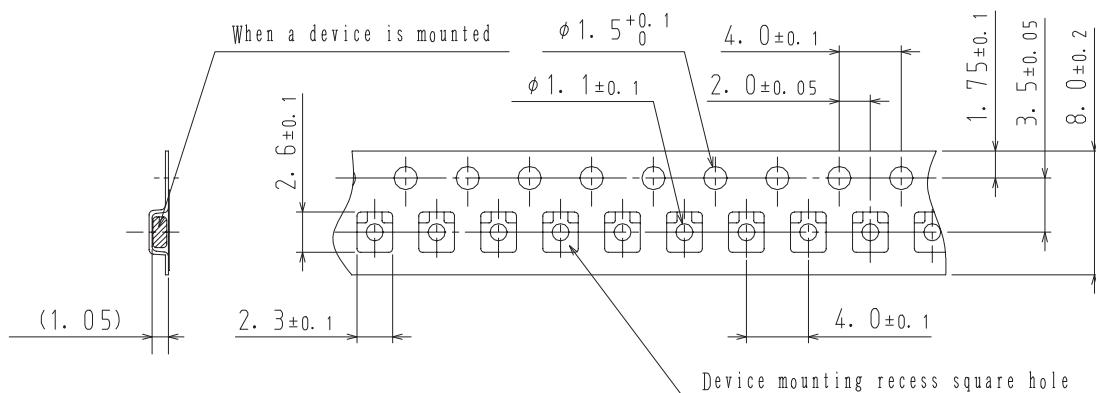
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
MCP	MCP	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

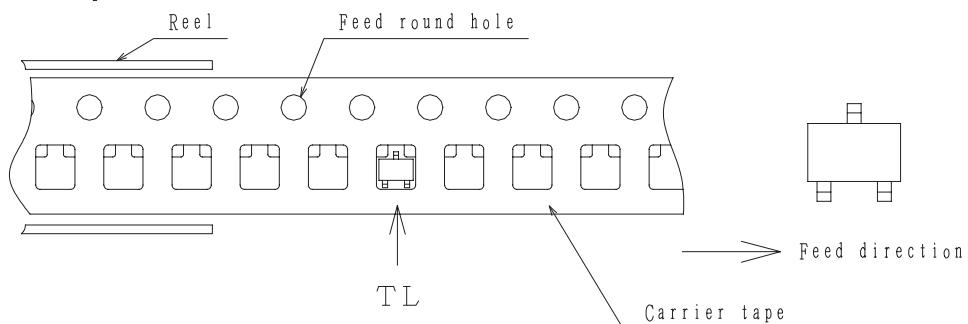


2. Taping configuration

2-1. Carrier tape size (unit:mm)



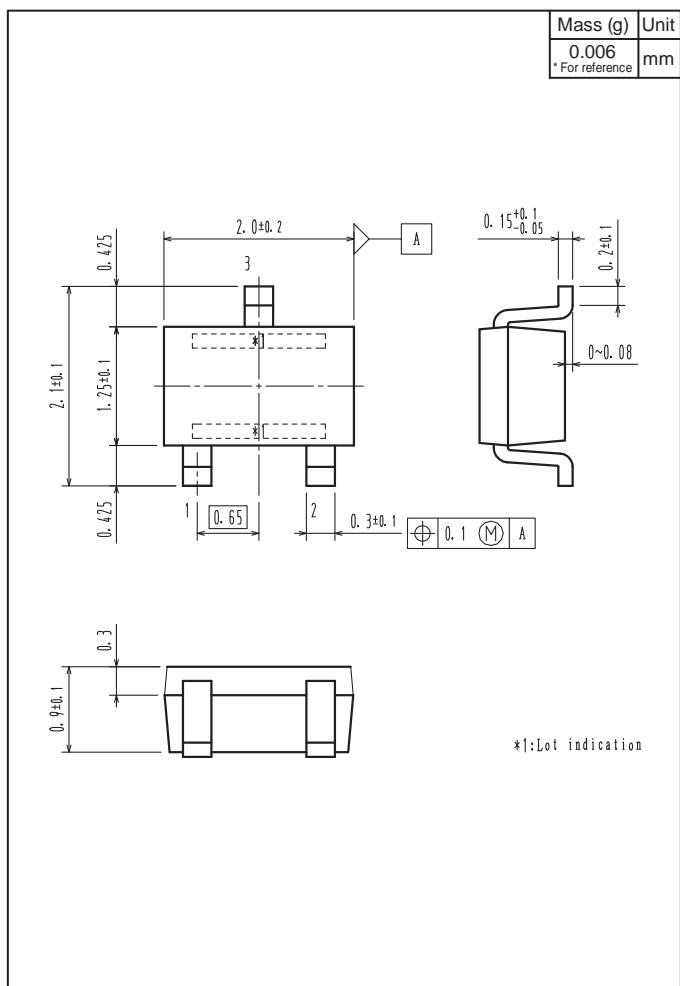
2-2. Device placement direction



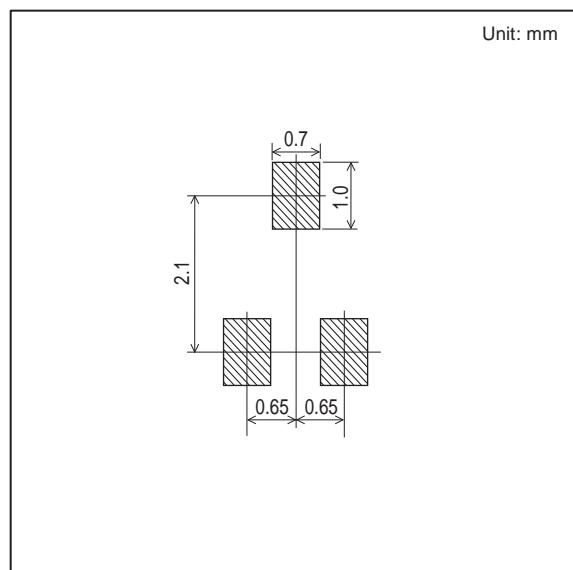
Those with open electrode terminal on the feed hole side.....TL

Outline Drawing

2SC4853A-4-TL-E



Land Pattern Example



- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment. The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for new introduction or other application different from current conditions on the usage of automotive device, communication device, office equipment, industrial equipment etc. , please consult with us about usage condition (temperature, operation time etc.) prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- Regarding monolithic semiconductors, if you should intend to use this IC continuously under high temperature, high current, high voltage, or drastic temperature change, even if it is used within the range of absolute maximum ratings or operating conditions, there is a possibility of decrease reliability. Please contact us for a confirmation.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of August, 2012. Specifications and information herein are subject to change without notice.